

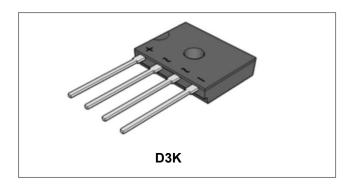
UG4KB05 THRU UG4KB100

Technical Data Data Sheet N1752, Rev. A



UG4KB05 THRU UG4KB100

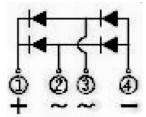
Single-Phase 4.0A Glass Passivated Bridge Rectifier



Features

- Glass passivated die construction
- Low forward voltage drop
- High current capability
- High surge current capability
- Designed for surface mount application
- Plastic material-UL flammability 94V-0
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: D3K, Molded plastic
- Terminals: Plated leads solderable per MIL-STD-202, Method 208
- Polarity: as marked on case
- Mounting Position: Any
- Lead Free: For RoHS / Lead Free Version

Maximum Ratings: @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Type Number	Symbol	UG4K B05	UG4K B10	UG4K B20	UG4K B40	UG4K B60	UG4K B80	UG4K B100	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{DC}	50	100	200	400	600	800	1000	v
RMS Reverse Voltage	V _{RMS}	35	70	140	280	420	560	700	V
Average Rectified Without heat sink $@T_A = 30^{\circ}C$ Output Current With heat sink $@T_A = 140^{\circ}C$	lo				2.0 4.0				А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	120			А				

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Type Number	Symbol	UG4K B05	UG4K B10	UG4K B20	UG4K B40	UG4K B60	UG4K B80	UG4K B100	Units
Forward Voltage (per element) * @I _F =4.0A	VF				1.1				V
Peak Reverse Current * @T _A = 25°C At Rated DC Blocking Voltage * @T _A = 125°C	I _R				5.0 500				μA
Typical Junction Capacitance(per leg) (Note 1)	CJ				21				pF

* Pulse width < 300 µs, duty cycle < 2%</p>

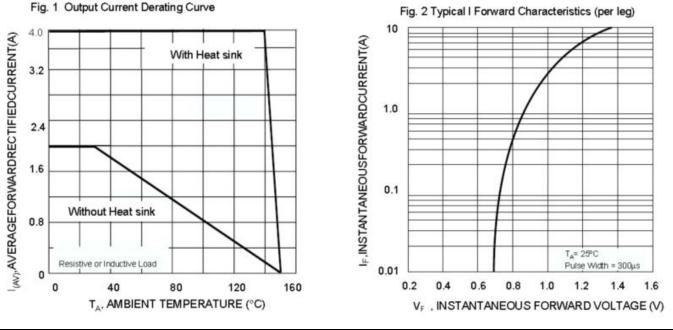
Thermal-Mechanical Specifications:

Type Number	Symbol	UG4K B05	UG4K B10	UG4K B20	UG4K B40	UG4K B60	UG4K B80	UG4K B100	Units
Typical Thermal Resistance (per leg)(Note 2)	R _{0JA} R _{0JL}	55 15			°C/W				
Operating and Storage Temperature Range	TJ, TSTG			-5	5 to +150	0			°C

Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

2. Mounted on glass epoxy PC board with 1.3mm² solder pad.

Ratings and Characteristics Curves



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UG4KB05 THRU **UG4KB100**

Po RoHS





RoHS 🗭

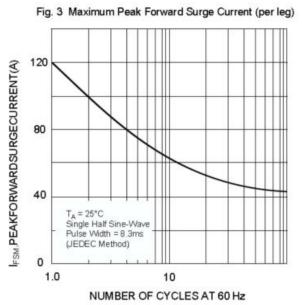
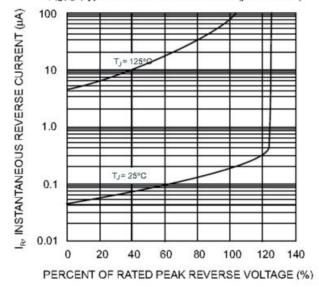


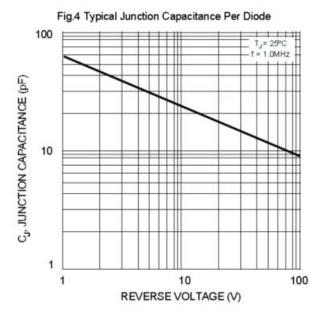
Fig. 5 T ypical Reverse Characteristics (per element)



Ordering Information

Device	Package	Plating	Shipping
UG4KB05 THRU UG4KB100	D3K(Pb-Free)	Pure Sn	37pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.



Marking Diagram



Where XXXXX is YYWWL

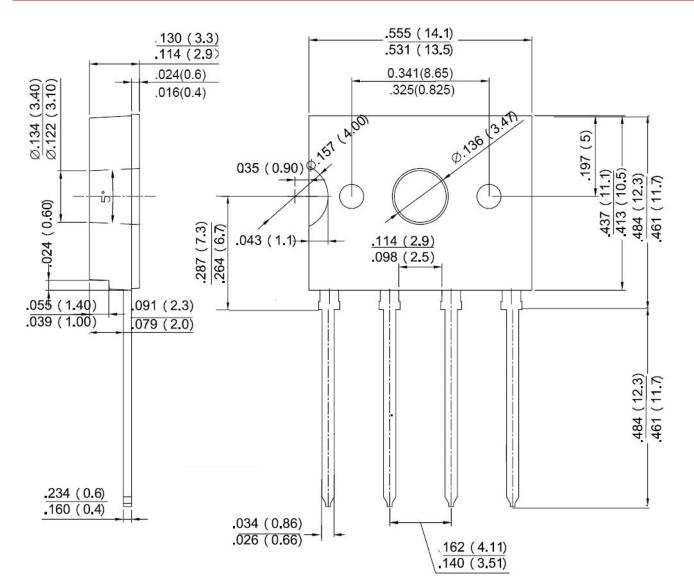
SSG	= SSG
YY	= Year
ww	= Week
_	= Lot Number
UG4KB05	= Type Number

Cautions: Molding resin Epoxy resin UL:94V-0

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Mechanical Dimensions D3K (Inches/Millimeters)





RoHS 🗭





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